## FEATURES

- Reverse Voltage 400 to 600 Volts
- Forward Current 1.0 Ampere
- Plastic package has Underwriters Laboratories

Flammability Classification 94V-0

- Ideally suited for use in very high frequency switching power supplies, inverters and as a free wheeling diode
- Ultrafast recovery time for high efficiency
- Glass passivated junction
- High temperature soldering guaranteed: $250^{\circ} \mathrm{C} / 10$ Seconds, $0.375^{\prime \prime}(9.5 \mathrm{~mm})$ lead length at 5 lbs . $(2.3 \mathrm{Kg})$ tension


## MECHANICAL DATA

- Cases: JEDEC DO-204AC(DO-15), molded plastic body over passivated chip


Dimensions in inches and (millimeters)
■ Terminals: Axial leads, solder-able per MIL-STD-750,
Method 2026

- Polarity: Color band denotes cathode end
- Mounting position: Any

■ Weight: 0.015 ounce, 0.4 gram

MAXIMUM RATINGS ( $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ unless otherwise specified)

| Parameter | Symbols | MUR140 | MUR160 | Units |
| :---: | :---: | :---: | :---: | :---: |
| Maximum repetitive peak reverse voltage | VRRM | 400 | 600 | Volts |
| Working peak reverse voltage | VRWM | 400 | 600 | Volts |
| Maximum DC blocking voltage | VDC | 400 | 600 | Volts |
| Maximum average forward rectified current at TA $=120^{\circ} \mathrm{C}$ | IF(AV) | 1.0 |  | Amp |
| Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load (JEDEC Method) | IFSM | 35.0 |  | Amps |
| Maximum instantaneous forward lat $\mathrm{F}=1.0 \mathrm{~A}, \mathrm{TJ}=25^{\circ} \mathrm{C}$ <br> voltage (Note 1) at IF $=1.0 \mathrm{~A}, \mathrm{TJ}=150^{\circ} \mathrm{C}$ | VF | 1.251 .05 |  | Volts |
| Maximum instantaneous reverse $\mathrm{TJ}=25^{\circ} \mathrm{C}$ <br> current at rated DC blocking $\mathrm{TJ}=150^{\circ} \mathrm{C}$ <br> voltage (Note 1)  | IR | 5.0150 |  | uA uA |
| Maximum reverse recovery time at $\mathrm{IF}=0.5 \mathrm{~A}, \mathrm{IR}=1.0 \mathrm{~A}, \mathrm{Irr}=0.25 \mathrm{~A}$ | trr | 50 |  | nS |
| Maximum reverse recovery time at $\mathrm{IF}=1.0 \mathrm{~A}, \mathrm{di} / \mathrm{dt}=50 \mathrm{~A} / \mathrm{us}, \mathrm{VR}$ $=30 \mathrm{~V}, \mathrm{Irr}=10 \%$ | trr | 75 |  | nS |
| Maximum forward recovery time at IF $=1.0 \mathrm{~A}$, di/dt=100A/us, recovery to 1.0 V | tfr | 50 |  | nS |
| Typical thermal resistance junction to ambient (Note 2) | R日JA | 50 |  | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
| Operating junction and storage temperature range | TJ, TSTG | -55 to +175 |  | ${ }^{\circ} \mathrm{C}$ |

NOTE: 1. Pulse test: $t p=300 u s$, duty cycle $<2 \%$
2. Lead length $=3 / 8^{\prime \prime}$ on P.C. Board with $1.5^{\prime \prime} \times 1.5^{\prime \prime}$ copper surface

RATINGS AND CHARACTERISTIC CURVES (TA $=25^{\circ} \mathrm{C}$, unless otherwise specified.)

Fig. 1 - Forward Current Derating Curve


Fig. 3 - Typical Instantaneous
Forward Characteristics (MUR160)


Fig. 5 - Typical Junction Capacitance


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current


Fig. 4 - Typical Reverse Leakage Characteristics (MUR160)


MUR140
MUR160

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